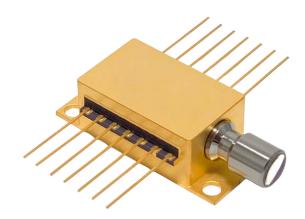
Beam Homogenized Stub Laser





Our proprietary multimode wavelength stabilized laser diode features high output power with narrow spectral bandwidth with a shaped and homogenized beam profile that evenly spreads out the power density and shapes the beam for different spot sizes or to match the field of view of a camera. Designed

to replace expensive DFB, DBR, fiber, and external cavity lasers, the multimode Spectrum Stabilized Laser offers superior wavelength stability over time, temperature (0.007 nm/°C), and vibration, and is manufactured to meet the most demanding wavelength requirements.

Standard Wavelengths

Applications

This laser package is designed for OEM Integration and is ideal for:

- Hand-held Raman spectroscopy
- Solid state laser pumping
- Laser speckle contrast imaging
- Laser illumination

Key Features

The stabilized peak wavelength remains "locked" regardless of case temperature (15 to 45 °C). Devices can be spectrally tailored to suit application needs & offer SMSRs better than 40 dB, providing extremely high signal to noise ratio. Multimode lasers come standard with <0.1 nm (0.08nm typical) spectral linewidth.

- High Power Open Beam Multimode output power.
- Shaped & Homogenized Beam 1:1, 1:2, or 1:3 beam aspect ratio.
- Even Power Distribution
- Available standard in rectangle or square shape output beam (ask about custom shapes)
- Ultra-Narrow Spectral Bandwidth (< 0.1 nm FWHM, 0.07 nm typical).
- Stabilized Output Spectrum (< 0.007 nm/2C)
- Low Power consumption
- 40 dB SMSR Typical
- 70 dB SMSR available upon request with additional filter

638 nm 785 nm 830nm 680nm 808 nm 1064 nm

Specifications



1350mA, 2.3V

1350mA, 2.2V

Wavelength Tolerance	+/- 0.5 nm	λ (nm)	Output Power (mW)	Base Part Number	Beam Aspect	Max Current, Voltage	Rectangle Direction	
Spectral Linewidth	<0.1nm, 0.07nm typical		Power (mvv)	Nullibel	Ratio	Current, voitage	Direction	
Wavelength		. ·	638	300*	RI0638MB0300B		1000mA,2.3V	
Stability Range			300	RI0680MB0300B		1350mA,2.3V		
SMSR	35 - 45 dB	785	350	RI0785MB0350B		1000mA,2.3V	Vertical	
SMSR w/integral laser line filter	60 - 70 dB	/65	600	RI0785MB0600B		1350mA, 2.3V		
laser lille lilter	1% typ., depending on timescale & operating conditions	808	350	RI0808MB0350B	1:2 (75/150)	1000mA, 2.3V		
Power Stability		808	600	RI0808MB0600B		1350mA, 2.3V		
		920	350	RI0830MB0350B		1000mA, 2.3V		
			030	600	RI0830MB0600B		1350mA, 2.3V	
Beam Exit Angle	< 3° Typical	1064	600	RI1064MB0600B		1350mA, 2.3V		
Beam Shape Aspect Ratio	Configurable				,			
Fast Axis Beam	10 mrad typ.,	638	300	RI0638MB0300B		1000mA, 2.3V		
Divergence	20 mrad max.	680	300	RI0680MB0300B		1350mA, 2.3V		
Slow Axis Beam	5 mrad typ.,	785	350	RI0785MB0350B		1000mA, 2.3V		
Divergence	10 mrad max.	/65	600	RI0785MB0600B		1350mA, 2.3V		
		808	350	RI0808MB0350B	2:1 (150/75)	1000mA, 2.3V	Horizontal	
		000	600	RI0808MB0600B		1350mA, 2.3V		
		830	350	RI0830MB0350B		1000mA, 2.3V		
		030	(00	DI000014D0400D		4050 4 001		

600

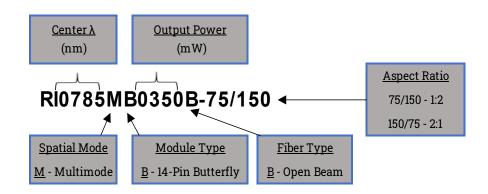
600

Part Schema

*Reduced wavelength stability range

RI0830MB0600B

RI1064MB0600B



1064

Selected Data

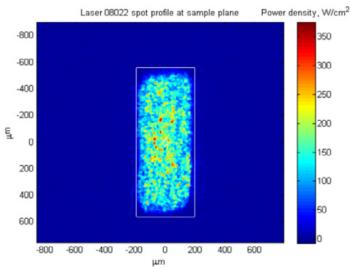




Beam Quality Stability λ + Power A

<pre><dfb-ld 40.1="" 784.*<="" :="" analy="" pk="" pre="" smsr="" wl=""></dfb-ld></pre>		DE OFFSET : -	0.724nm B:	MAX HLD /BLK MIN HLD /BLK WRITE /DSF
10.0dB/D 27.6	RES:0.01	nm SENS:MID	AUG: 1	SMPL:AUTO
		og		
7.6REF dBm		T A		
124				
324		•		
024				
524 780.00nm		785.00nm	1.00nm/D	790.00nr

TEC Current Limit	3.2 A
TEC Voltage Limit	5.8 V
Photodiode Current	30uA
Integral Thermistor	Betatherm 10K3CG3



Custom Capability

- Custom wavelengths available upon request
- External TEC (e.g. No TEC inside of package optional)
- Additional Beam Homogenizer Option:

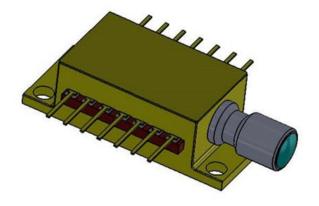
Beam Aspect Ratio	NA
150 x 300 μm	0.22 NA
75 x 150 μm	0.22 NA
50 x 150 μm	0.21 NA
33 x 100 μm	0.15 NA
50 x 50 μm	0.22 NA

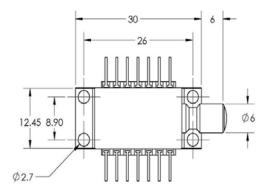
Electrical Specs

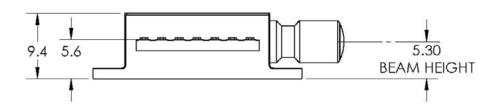
Pin 1	TEC +		
Pin 2	Thermistor - 10K Ohm @ 25 C°		
Pin 3	PD Anode		
Pin 4	PD Cathode		
Pin 5	Thermistor		
Pin 6 - 8	NC		
Pin 9	Laser Cathode (-)		
Pin 10	Laser Anode (+)		
Pin 11	Laser Cathode (-)		
Pin 12	NC		
Pin 13	Case Ground		
Pin 14	TEC -		

Mechanical Drawings









OEM Laser Product: This laser module is designed for use as a component (or replacement) part and is thereby exempt from 21 CFR1040.10 and 1040.11 provisions.

Operational Notes

- 1. 14-pin BF should be mounted on a heat sink with a thermal compound (thermal grease).
- 2. Take care not to over-tighten screws when mounting. This can bend the BF package causing damage and hindering performance, and is not covered under warranty.
- 3. Laser and TEC driver circuitry should be configured in a manner to prevent power /current / voltage surges and spikes.
- 4. We recommend not grounding anode and cathode as this can cause ground loops.
- 5. TECs require optimization of PID controller parameters in customer specific application (e.g. ambient temperature, TEC controller, heat sinking etc.) to prevent overtemperature surges that could damage the laser diode.
- 6. Spot starts out rectangular and has a lens with a focal length of 7.5 mm. We recommend adding a second lens to image the rectangular beam to the spot size that you would like. The laser is focused to infinity.









